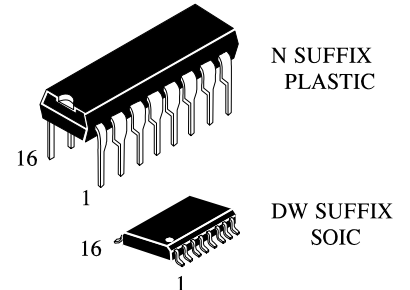


# IW4019B

## Quad AND/OR Select Gate High-Voltage Silicon-Gate CMOS

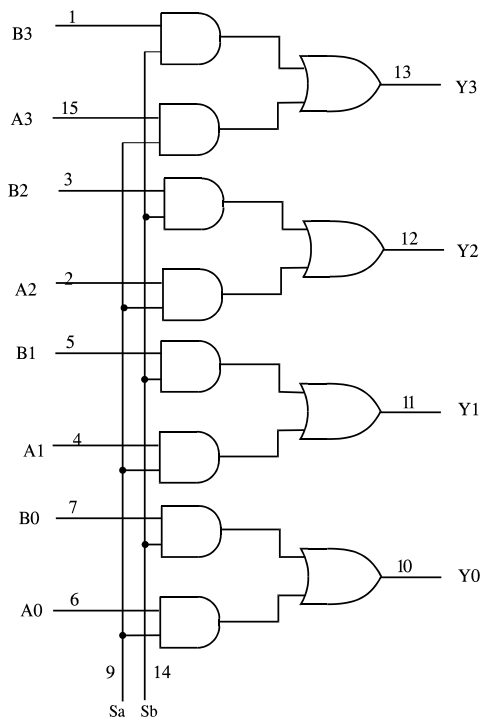
The IW4019B types consist of four AND/OR select gate configurations, each consisting of two 2-input AND gates driving a single 2-input gate. Selection is accomplished by control bits  $S_a$  and  $S_b$ . In addition to selection of either channel A or channel B information, the control bits can be applied simultaneously to accomplish the logical A + B function

- Operating Voltage Range: 3.0 to 18 V
- Maximum input current of 1  $\mu$ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):  
1.0 V min @ 5.0 V supply  
2.0 V min @ 10.0 V supply  
2.5 V min @ 15.0 V supply



**ORDERING INFORMATION**  
**IW4019BN Plastic**  
**IW4019BDW SOIC**  
**TA = -55° to 125° C for all packages**

### LOGIC DIAGRAM



PIN 16 =  $V_{CC}$   
 PIN 8 = GND

### PIN ASSIGNMENT

B3	1	16	$V_{CC}$
A2	2	15	A3
B2	3	14	$S_b$
A1	4	13	Y3
B1	5	12	Y2
A0	6	11	Y1
B0	7	10	Y0
GND	8	9	$S_a$

### FUNCTION TABLE

Inputs				Outputs
$S_a$	$S_b$	A	B	Y
H	L	H	X	H
H	L	L	X	L
L	H	X	H	H
L	H	X	L	L
L	L	X	X	L
H	H	L	L	L
H	H	L	H	H
H	H	H	L	H
H	H	H	H	H

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### MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +20	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±10	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
P <sub>D</sub>	Dissipation per Output Transistor	100	mW
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: : - 7 mW/°C from 65° to 125°C

### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	3.0	18	V
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V<sub>IN</sub> and V<sub>OUT</sub> should be constrained to the range  $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

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## DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter		Test Conditions	V <sub>CC</sub> V	Guaranteed Limit			Unit
					≥-55°C	25°C	≤125°C	
V <sub>IH</sub>	Minimum High-Level Input Voltage	High-Input	V <sub>OUT</sub> =0.5V or V <sub>CC</sub> - 0.5V	5.0	3.5	3.5	3.5	V
			V <sub>OUT</sub> =1.0V or V <sub>CC</sub> - 1.0V	10	7	7	7	
			V <sub>OUT</sub> =1.5V or V <sub>CC</sub> - 1.5V	15	11	11	11	
V <sub>IL</sub>	Maximum Low-Level Input Voltage	Low-Input	V <sub>OUT</sub> =0.5V or V <sub>CC</sub> - 0.5V	5.0	1.5	1.5	1.5	V
			V <sub>OUT</sub> =1.0V or V <sub>CC</sub> - 1.0V	10	3	3	3	
			V <sub>OUT</sub> =1.5V or V <sub>CC</sub> - 1.5V	15	4	4	4	
V <sub>OH</sub>	Minimum High-Level Output Voltage	High-Output	V <sub>IN</sub> =GND or V <sub>CC</sub>	5.0	4.95	4.95	4.95	V
				10	9.95	9.95	9.95	
				15	14.95	14.95	14.95	
V <sub>OL</sub>	Maximum Low-Level Output Voltage	Low-Output	V <sub>IN</sub> =GND or V <sub>CC</sub>	5.0	0.05	0.05	0.05	V
				10	0.05	0.05	0.05	
				15	0.05	0.05	0.05	
I <sub>IN</sub>	Maximum Input Leakage Current		V <sub>IN</sub> = GND or V <sub>CC</sub>	18	±0.1	±0.1	±1.0	μA
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)		V <sub>IN</sub> = GND or V <sub>CC</sub>	5.0	1	1	30	μA
				10	2	2	60	
				15	4	4	120	
				20	20	20	600	
I <sub>OL</sub>	Minimum Low Output Current (Sink)	Output (Sink)	V <sub>IN</sub> = GND or V <sub>CC</sub>					mA
			U <sub>OL</sub> =0.4 V	5.0	0.64	0.51	0.36	
			U <sub>OL</sub> =0.5 V	10	1.6	1.3	0.9	
I <sub>OH</sub>	Minimum High Output Current (Source)	Output (Source)	V <sub>IN</sub> = GND or V <sub>CC</sub>					mA
			U <sub>OH</sub> =2.5 V	5.0	-2.0	-1.6	-1.15	
			U <sub>OH</sub> =4.6 V	5.0	-0.64	-0.51	-0.36	
			U <sub>OH</sub> =9.5 V	10	-1.6	-1.3	-0.9	
			U <sub>OH</sub> =13.5 V	15	-4.2	-3.4	-2.4	

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## AC ELECTRICAL CHARACTERISTICS ( $C_L=50\text{pF}$ , $R_L=200\text{K}\Omega$ , Input $t_r=t_f=20\text{ ns}$ )

Symbol	Parameter	$V_{CC}$ V	Guaranteed Limit			Unit
			$\geq -55$ $^{\circ}\text{C}$	$25^{\circ}\text{C}$	$\leq 125$ $^{\circ}\text{C}$	
$t_{PLH}$ , $t_{PHL}$	Maximum Propagation Delay, Input A, B, $S_A$ or $S_b$ to Output Y (Figure 1)	5.0 10 15	300 120 100	300 120 100	600 240 200	ns
$t_{TLH}$ , $t_{THL}$	Maximum Output Transition Time, Any Output (Figure 1)	5.0 10 15	200 100 80	200 100 80	400 200 160	ns
$C_{IN}$	Maximum Input Capacitance	All A and B Inputs	-		7.5	pF
		$S_a$ and $S_b$ Inputs	-		15.0	pF

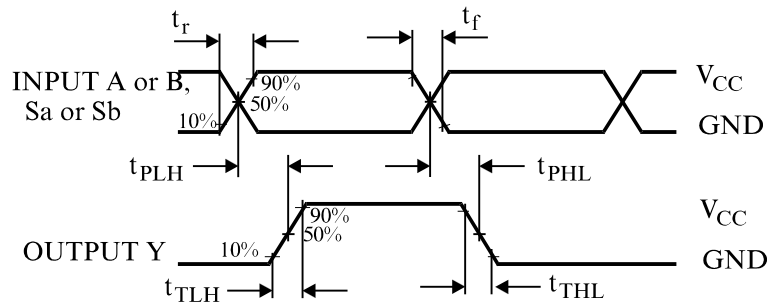


Figure 1. Switching Waveforms

### EXPANDED LOGIC DIAGRAM (1/4 of the Device)

